

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,547,909 B2
APPLICATION NO. : 10/597607
DATED : June 16, 2009
INVENTOR(S) : Joongseo Park

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title Page, Item (54) and Column 1, lines 1-3

Please delete "III_NITRIDE COMPOUND ICE SEMICONDUCTOR LIGHT
EMITTING DEV" and insert --III-NITRIDE COMPOUND SEMICONDUCTOR
LIGHT EMITTING DEVICE--

Title Page, Item (22)

Please delete "March 5, 2005" and insert --February 5, 2005--

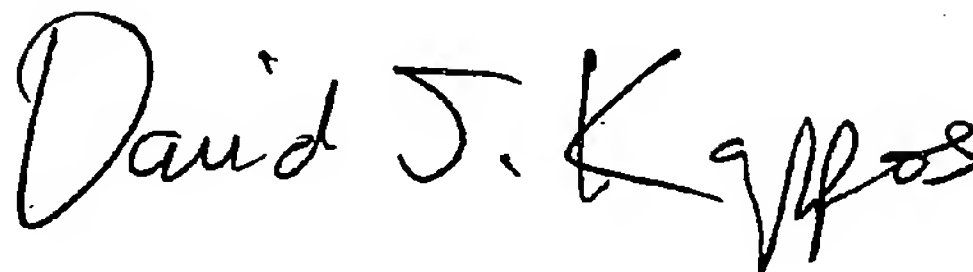
Title Page, Item (86)

For the filing or '371c' date, delete "August 1, 2006" and insert --August 3,
2006--

This certificate supersedes the Certificate of Correction issued September 15, 2009.

Signed and Sealed this

Sixth Day of October, 2009

A handwritten signature in black ink, reading "David J. Kappos". The signature is written in a cursive, flowing style with a large initial 'D' and 'K'.

David J. Kappos
Director of the United States Patent and Trademark Office